## 山东晶导微电子股份有限公司 Jingdao Microelectronics co.LTD MBR2040xT THRU MBR20200xT

## SCHOTTKY BARRIER RECTIFIERS

Reverse Voltage - 40 to 200 V

Forward Current - 20 A

### FEATURES

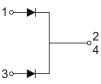
- High current capability
- Low forward voltage drop
- Low power loss, high efficiency
- High surge capability
- High temperature soldering guaranteed
- Mounting position: any

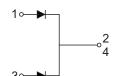


TO-252(D-PAK)









### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25  $^\circ\!C$  ambient temperature unless otherwise specified

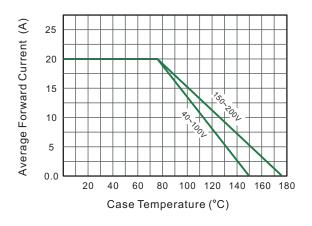
CHARACTERISTICS	TO-251	MBR2040VT	MBR2045VT	MBR2060VT	MBR20100VT	MBR20150VT	MBR20200VT	Units	
CHARACTERISTICS	TO-252	MBR2040DT	MBR2045DT	MBR2060DT	MBR20100DT	MBR20150DT	MBR20200DT		
Maximum Recurrent Peak Reverse Voltage	$V_{\text{RRM}}$	40	45	60	100	150	200	V	
Maximum RMS voltage	$V_{\text{RMS}}$	28	31.5	42	70	105	140	V	
Maximum DC Blocking Voltage	$V_{\text{DC}}$	40	45	60	100	150	200	V	
Maximum Average Forward Rectified Current	I <sub>F(AV)</sub>			2	0			А	
Peak Forward Surge Current,8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	perimposed I <sub>FSM</sub> 150								
Max Instantaneous Forward Voltage at 10 A DC per leg	V <sub>F</sub>	0.	70	0.75	0.85	0.90	0.92	V	
Maximum DC Reverse Current T <sub>a</sub> = 25°C at Rated DC Reverse Voltage T <sub>a</sub> =125°C	I <sub>R</sub>		0.1 20			0.05 20	mA		
Typical Junction Capacitance <sup>(1)</sup>	Cj	600 400						рF	
Typical Thermal Resistance <sup>(2)</sup>	Thermal Resistance <sup>(2)</sup> R <sub>0JA</sub> 45								
Operating Junction Temperature Range	Junction Temperature Range T <sub>j</sub> -55 ~ +150 -55 ~ +175								
Storage Temperature Range	T <sub>stg</sub>	-55 ~ +150 -55 ~ +175							

( 1 ) Measured at 1 MHz and applied reverse voltage of 4 V D.C

( 2 ) P.C.B. mounted with 10cmX10cmX1mm copper pad areas.

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#### Fig.1 TYPICAL FORWARD CURRENT DERATING CURVE



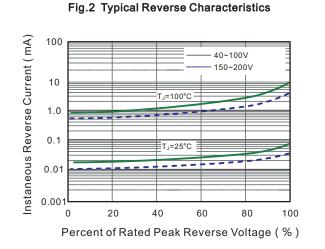


Fig.3 Typical Forward Characteristic

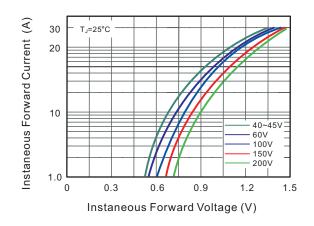
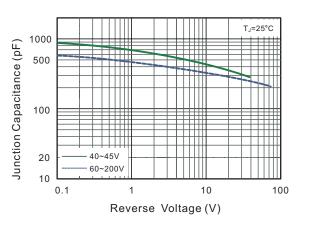
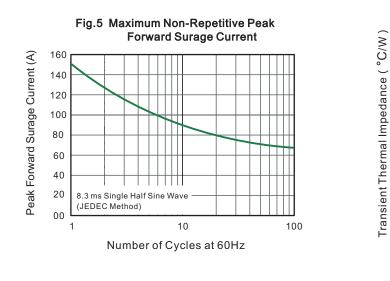
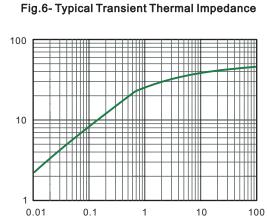


Fig.4 Typical Junction Capacitance

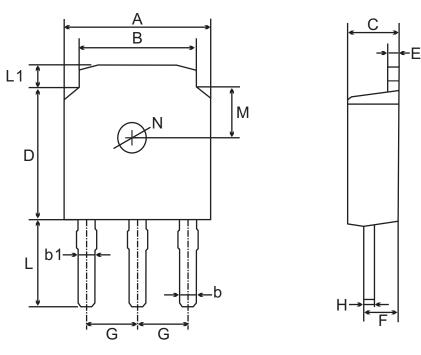






t, Pulse Duration (sec)

## TO-251(D-PAK) Package Outline Dimensions



### TO-251(I-PAK) mechanical data

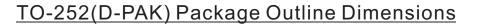
	UN	IIT	A	В	b	b1	С	D	Е	F	G	н	L L1		М	N
	mm max min	6.7	5.5	0.8	0.9	2.5	6.3	0.6	1.8	2.29	0.55	4.3	1.2	1.8	1.3	
		min	6.3	5.1	0.3	0.76	2.1	5.9	0.4	1.3	TYPICAL	0.45	3.9	0.8	TYPICAL	TYPICAL
	mil	max	264	217	31	35	98 248 24 71 90	90	22	169	47	71	51			
	mii	min	248	201	12	30	83	232	16	51	TYPICAL	18	154	31	TYPICAL	TYPICAL

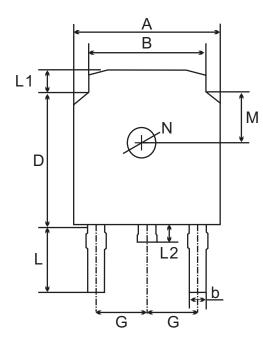
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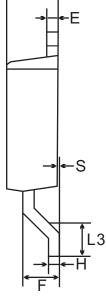
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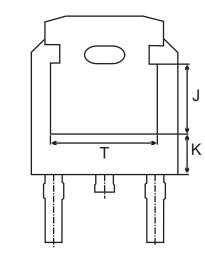
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TO-252(D-PAK) mechanical data

U	Π	А	В	b	С	D	Е	F	G	Н	L	L1	L2	L3	S	М	Ν	J	К	Т
mm	max	6.7	5.5	0.8	2.5	6.3	0.6	1.8	2.29	0.55	3.1	1.2	1.0	1.75	0.1	1.8 TYPICAL	-			4.83 ref.
	min	6.3	5.1	0.3	2.1	5.9	0.4	1.3	TYPICAL	0.45	2.7	0.8	0.6	1.40	0.0					
I	max	264	217	31	98	248	24	71	90	22	122	47	39	69	4	71	51	124	71	190
mil	min	248	201	12	83	232	16	51	TYPICAL	18	106	31	24	55	0	TYPICAL	TYPICAL	ref.	ref.	ref.

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